TL322C, TL322I DUAL LOW-POWER OPERATIONAL AMPLIFIERS

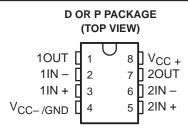
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- Wide Range of Supply Voltages
 Single Supply . . . 5 V to 30 V
 Dual Supplies . . . ± 2.5 V to ± 15 V
- Class AB Output Stage
- True Differential Input Stage
- Low Input Bias Current
- Internal Frequency Compensation
- Short-Circuit Protection

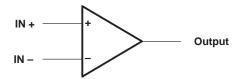
description

The TL322C and the TL322I are dual operational amplifiers similar in performance to the uA741 but with several distinct advantages. They are designed to operate from a single supply over a range of voltages from 5 V to 30 V. Operation from split supplies is also possible provided the difference between the two supplies is 5 V to 30 V. The common-mode input range includes the negative supply. Output range is from the negative supply to $V_{\rm CC}$ –1.5 V. Quiescent supply currents per amplifier are typically less than one-half those of the uA741.

The TL322C is characterized for operation from 0°C to 70°C. The TL322I is characterized for operation from -40°C to 85°C.



symbol (each amplifier)

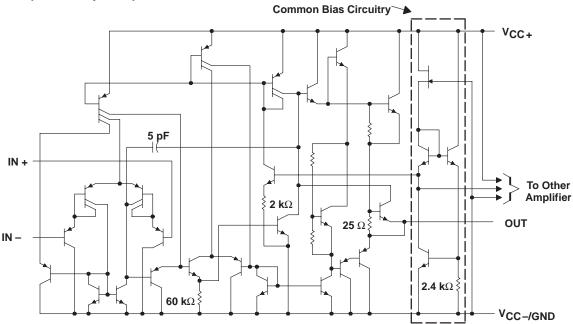


AVAILABLE OPTIONS

		PACKAGE					
TA	V _{IO} MAX AT 25°C	SMALL OUTLINE (D)	PLASTIC DIP (P)				
0°C to 70°c	10 mV	TL322CD	TL322CP				
0°C to 70°c	8 mV	TL322ID	TL322IP				

D packages are available taped and reeled. Add R suffix to device type, (e.g., TL322CDR).

schematic (each amplifier)



All component values shown are nominal.

Texas VI

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

	TL322C	TL322I	UNIT	
Supply voltage V _{CC+} (see Note 1)	18	18	V	
Supply voltage V _{CC} (see Note 1)	-18	-18	V	
Supply voltage V _{CC+} (with respect to V _{CC-})	36	36	V	
Differential input voltage (see Note 2)	±36	±36	V	
Input voltage (see Notes 1 and 3)	±18	±18	V	
Continuous total power disspation	See Dissipation Rating Table			
Operating free-air temperature range	0 to 70	-40 to 85	°C	
Storage temperature range	-65 to 150	-65 to 150	°C	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260	260	°C	

- NOTES: 1. These voltage values are with respect to the midpoint between V_{CC+} and V_{CC-}.
 - 2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.
 - 3. Neither input must ever be more positive than V_{CC+} or more negative than V_{CC-} .

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{A}} \leq 25^{\circ}\mbox{C}$ POWER RATING	DERATING FACTOR	DERATE ABOVE T _A	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
D	680 mW	5.8 mW/°C	33°C	464 mW	377 mW
Р	680 mW	8.0 mW/°C	65°C	640 mW	520 mW

recommended operating conditions

	MIN	NOM MAX	UNIT
Single supply voltage, VCC	5	30	V
Dual supply voltage, V _{CC+}	2.5	15	V
Dual supply voltage, V _{CC} _	- 2.5	- 15	V



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electrical characteristics at specified free-air temperature, $V_{\text{CC}\pm}$ = 15 V (unless otherwise noted)

	DADAMETED	TEST CONDITIONS [†]		TL322C		TL322I			UNIT	
	PARAMETER	IEST CONDI	HONSI	MIN	TYP	MAX	MIN	TYP	MAX	UNII
VIO	Input offset voltage	$V_{O} = 0,$	25°C		2	10		2	8	mV
VIO		$R_S = 50 \Omega$	Full range			12			10	111 V
αΛΙΟ	Temperature coefficient of input offset voltage	$V_O = 0$, $R_S = 50 \Omega$	25°C		10			10		μV/°C
IIO	Input offset current	V _O = 0	25°C		30	50		30	75	nA
10	input onset current	10-0	Full range			200			250	ПА
αΙΙΟ	Temperature coefficient of input offset current	V _O = 0	25°C		50			50		pA/°C
lin	Input bigg gurrent	Va = 0	25°C		-0.2	-0.5		-0.2	-0.5	
IB	Input bias current	VO = 0	Full range			-0.8			-1	μΑ
	Common made innut			VCC-	VCC-		VCC-	VCC-		
^V ICR	Common-mode input voltage range‡		25°C	to	to		to	to		V
	voltago rango.			13	13.5		13	13.5		
		R _L = 10 kΩ	25°C	±12	±13.5		±12	±12.5		
Vом	Peak output voltage swing	D 010	25°C	±10	±13		±10	±12		V
		$R_L = 2 k\Omega$	Full range	±10			±10			
	Large-signal differential voltage amplification	$V_0 = \pm 10 \text{ V},$	25°C	20	200		20	200		
AVD		$R_L = 2 k\Omega$	Full range	15			15			V/mV
ВОМ	Maximum-output- swing bandwidth	$V_{O(PP)} = 20 \text{ V},$ $A_{VD} = 1,$ $THD \le 5\%,$ $R_{L} = 2 \text{ k}\Omega$	25°C		9			9		kHz
B ₁	Unity-gain bandwidth	$V_O = 50 \text{ mV},$ $R_L = 10 \text{ k}\Omega$	25°C		1			1		MHz
φm	Phase margin	$R_L = 2 k\Omega$, $C_L = 200 pF$	25°C		60°			60°		
rį	Input resistance	f = 20 Hz	25°C	0.3	1		0.3	1		MΩ
r _O	Output resistance	f = 20 Hz	25°C		75			75		Ω
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR} \text{ min},$ $R_S = 50 \Omega$	25°C	70	90		70	90		dB
ksvs	Supply voltage sensitivity (ΔV _{IO} / ΔV _{CC})	$V_{CC} = \pm 2.5 \text{ V to}$ $\pm 15 \text{ V},$ $R_S = 50 \Omega$	25°C		30	150		30	150	μV/V
los	Short-circuit output current§	VO = 0	25°C	±10	±30	±45	±10	±30	±45	mA
ICC	Total supply current	$V_O = 0$, No load	25°C		1.4	4		1.4	4	mA

[†] All characteristics are under open-loop conditions unless otherwise noted. Full range for T_A is $0^{\circ}C$ to $70^{\circ}C$ for TL322C and $-40^{\circ}C$ to $85^{\circ}C$ for TL322I.



[‡] The V_{ICR} limits are directly linked volt-for-volt to supply voltage; the positive limit is 2 V less than V_{CC+}.

[§] Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

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electrical characteristics, V_{CC+} = 5 V, V_{CC-} = 0 V, T_A = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONST		TL322C		TL322I			UNIT
	PARAMETER	TEST CONDITIONS!	MIN	TYP	MAX	MIN	TYP	MAX	UNII
V _{IO}	Input offset voltage	$V_0 = 2.5 \text{ V}, R_S = 50 \Omega$		2	10			8	mV
IIO	Input offset current	V _O = 2.5 V		30	50			75	nA
I _{IB}	Input bias current			-0.2	-0.5			-0.5	рА
		$R_L = 10 \text{ k}\Omega$	3.3	3.5		3.3	3.5		
VOM	Peak output voltage swing [‡]	$R_L = 10 \text{ k}\Omega$,	V _{CC+} -1.7	1.7		V 4.7			V
		$V_{CC+} = 5 \text{ V to } 30 \text{ V}$		1.7		V _{CC+} -1.7			
	Large-signal differential	V _O = 1.7 V to 3.3 V,	20	000		-00	000		
AVD	voltage amplification	$R_L = 2 k\Omega$	20	200		20	200		V/mV
ksvs	Supply voltage sensitivity $(\Delta V_{IO}/\Delta V_{CC}+)$	V _{CC} = ±2.5 V to ±15 V			150			150	μV/V
Icc	Supply current	V _O = 2.5 V, No load		1.2	4		1.2	4	mA
V ₀₁ /V ₀₂	Crosstalk attenuation	A _{VD} = 100, f = 1 kHz to 20 kHz		120			120		dB

 $[\]ensuremath{^{\dagger}}\xspace$ All characteristics are specified under open-loop conditions.

switching characteristics, $V_{CC+} = 15 \text{ V}$, $V_{CC-} = -15 \text{ V}$ $A_{VD} = 1$, $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN TYP MAX	UNIT
SR	Slew rate at unity gain	$V_I = \pm 10 \text{ V}$, $C_L = 100 \text{ pF}$, See Figure 1	0.6	V/µs
t _r	Rise time	11/ 50 m/ 0 400 m5 B 4010	0.35	μs
tf	Fall time	$\Delta V_O = 50$ mV, $C_L = 100$ pF, $R_L = 10$ k Ω , See Figure 1	0.35	μs
	Overshoot factor	See Figure 1	20%	
	Crossover distortion	$V_{I(PP)} = 30 \text{ mV}, V_{O(PP)} = 2 \text{ V}, f = 10 \text{ kHz}$	1%	

PARAMETER MEASUREMENT INFORMATION

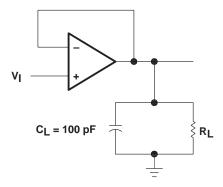


Figure 1. Unity-Gain Amplifier

[‡] Output will swing essentially to ground.

TYPICAL CHARACTERISTICS[†]

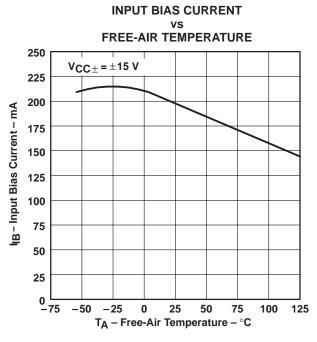
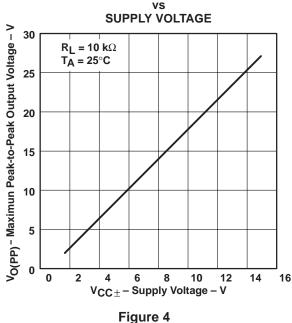


Figure 2

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE



INPUT BIAS CURRENT vs SUPPLY VOLTAGE

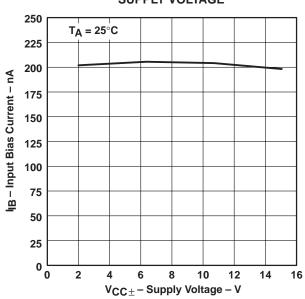


Figure 3

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE

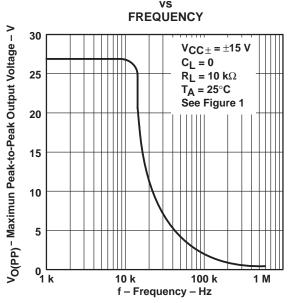


Figure 5

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION

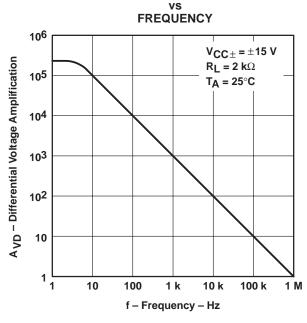


Figure 6

VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE

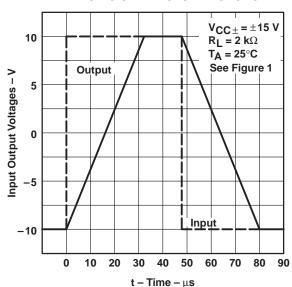


Figure 7

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